SHINDENGEN

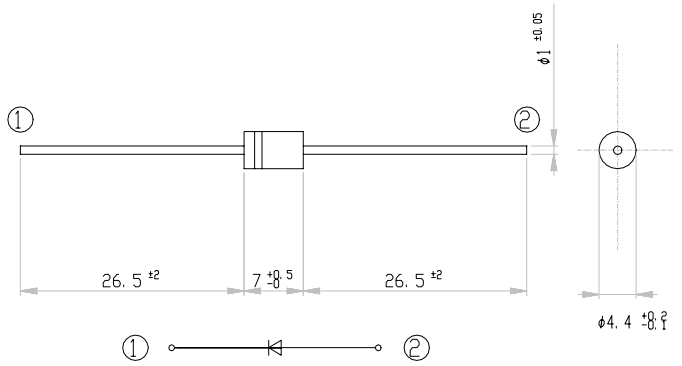
Sidac

K1V11

OUTLINE DIMENSIONS

Case : AX10

(Unit : mm)



RATINGS

●Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		−40～125	℃
Operating Junction Temperature	Tj		125	℃
Maximum Off-state Voltage	V_{DRM}		90	V
RMS On-state Current	I_T	Tl = 112℃, 50Hz sine wave (θ = 180°)	1	A
Surge On-state Current	I_{TSM}	Tj = 25℃, 50Hz sine wave (θ = 180°), non-repetitive 1-cycle peak value	20	A
Pulse On-state Current	I_{TRM}	Ta =25 ℃, pulse width t_o = 10 μs, sine wave, repetitive peak value f = 1 kHz	25	A
		Ta =25 ℃, pulse width t_o = 10 μs, sine wave, repetitive peak value f = 60 Hz	80	
Critical Rate of Rise of On-state Current	di_T/dt		80	A/μs

●Electrical Characteristics (Tl=25℃)

Item	Symbol	Conditions	Ratings	Unit
Breakover Voltage	V_{BO}	I_B = 0, 50Hz sine wave	104～118	V
Off-state Current	I_{DRM}	$V_D = V_{DRM}$	Max 10	μA
Breakover Current	I_{BO}		Max 0.5	mA
Holding Current	I_H		TYP 50	mA
On-state Voltage	V_T	I_T = 1A	Max 1.5	V
Switching Resistance	R_S		Min 0.1	kΩ
Thermal Resistance	θ jl	Junction to lead	Max 15	℃/W

●Standard Design with P.C.B.

Item	Symbol	Conditions	Standard	Unit
RMS On-state Current	I_T	Assembled in P.C.B., Ta = 25℃, soldering land 3mm φ	1.2	A

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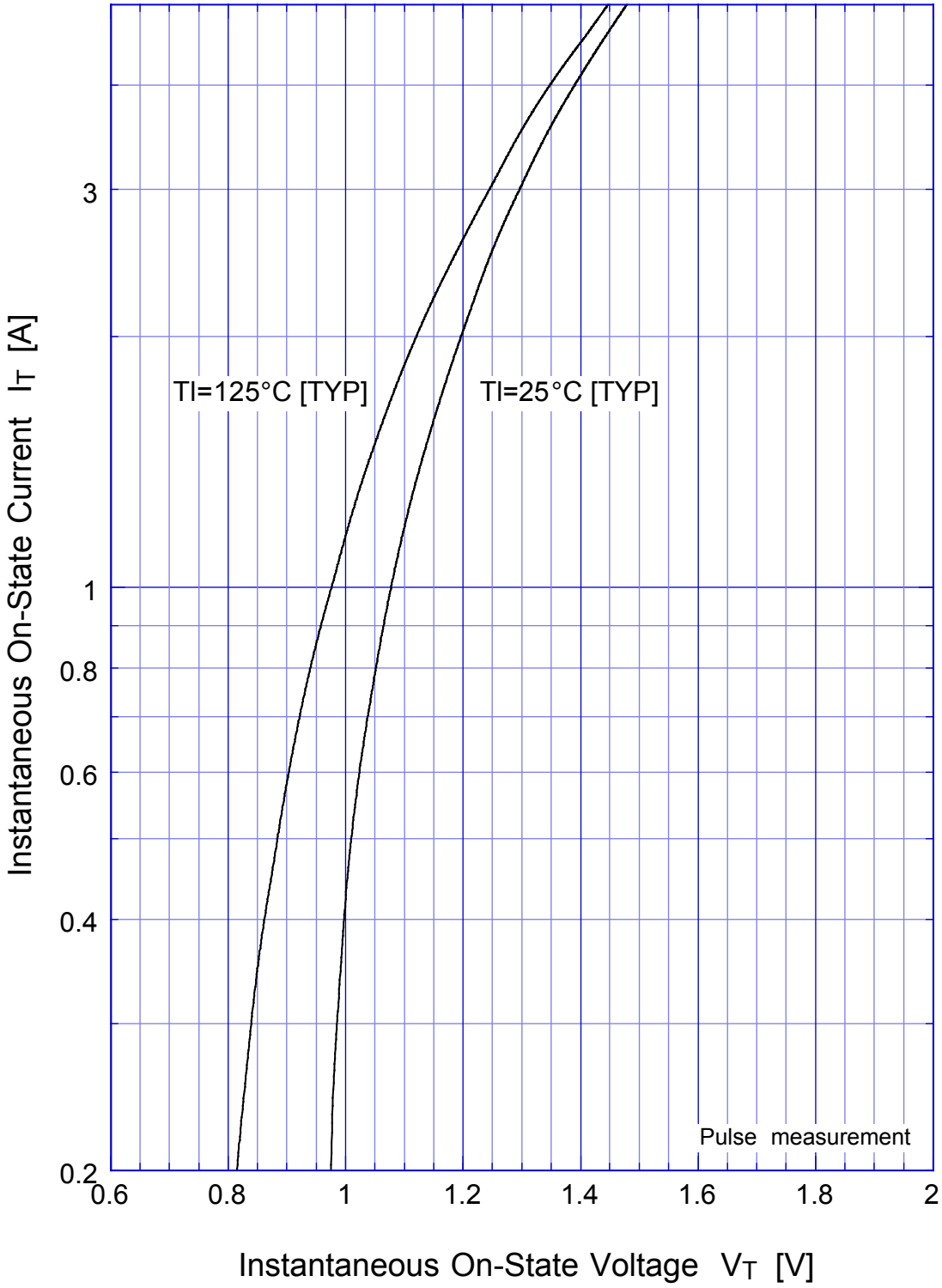
Typical On-State Voltage



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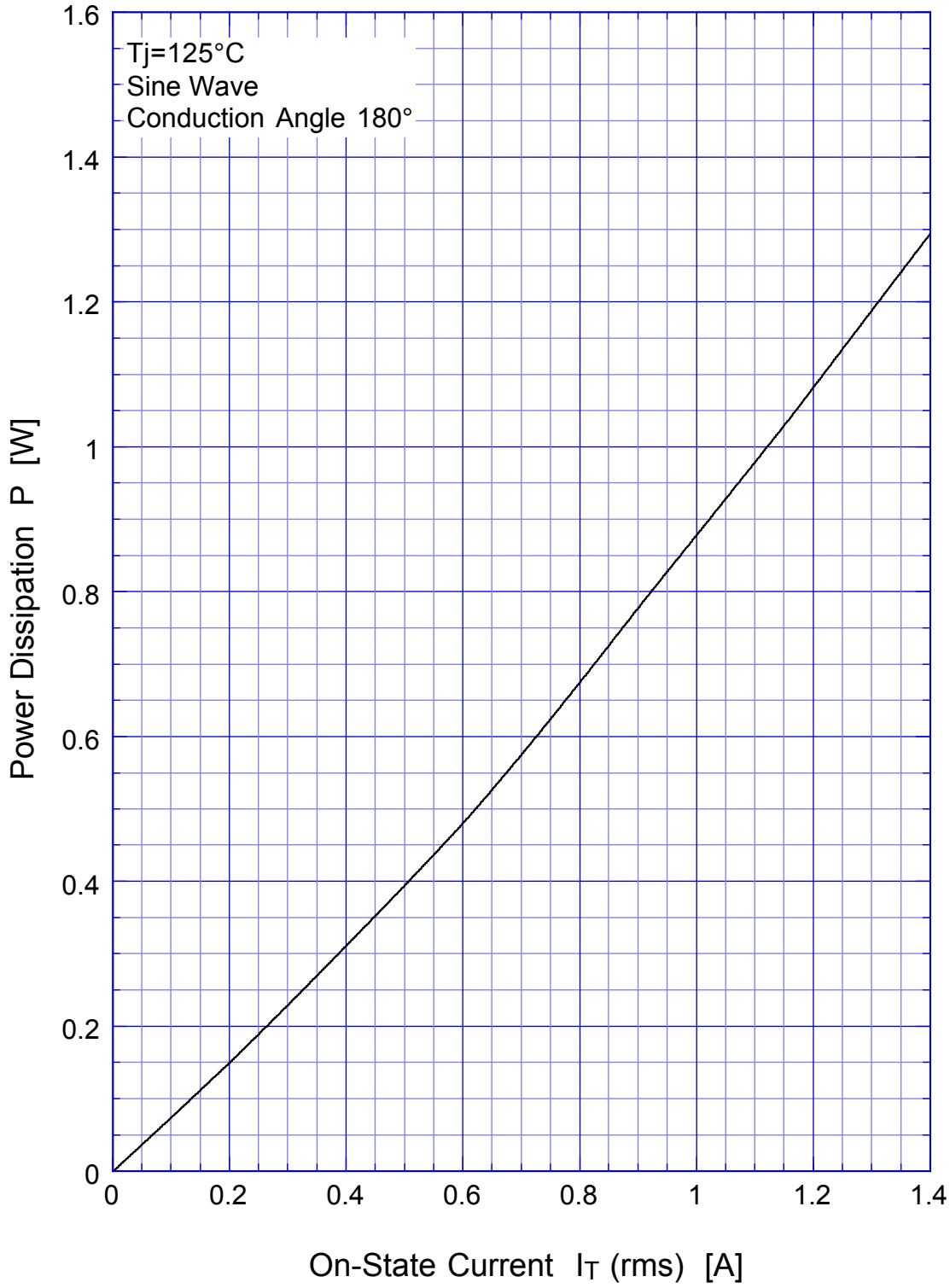
Power Dissipation



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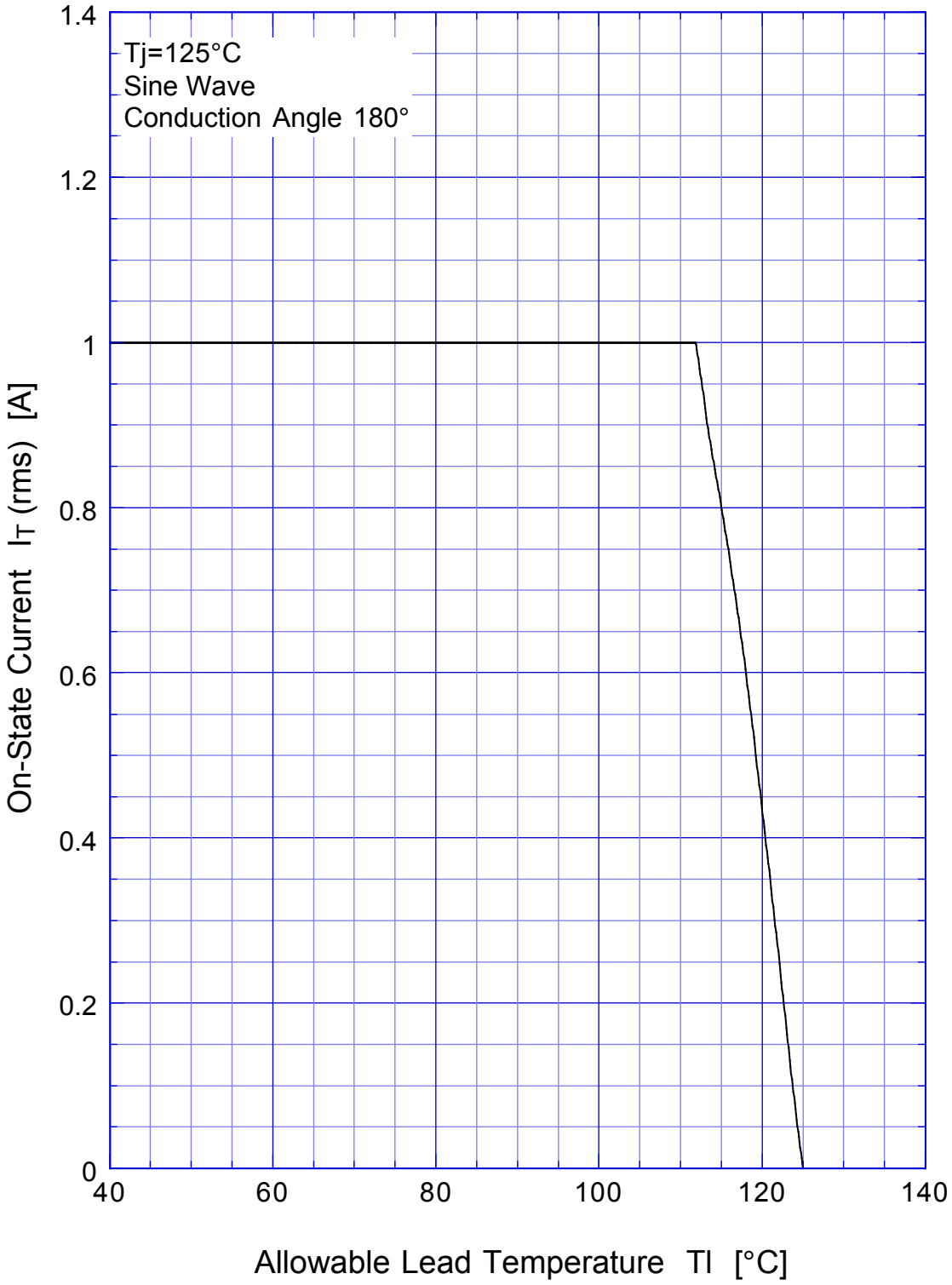
Maximum Lead Temperature



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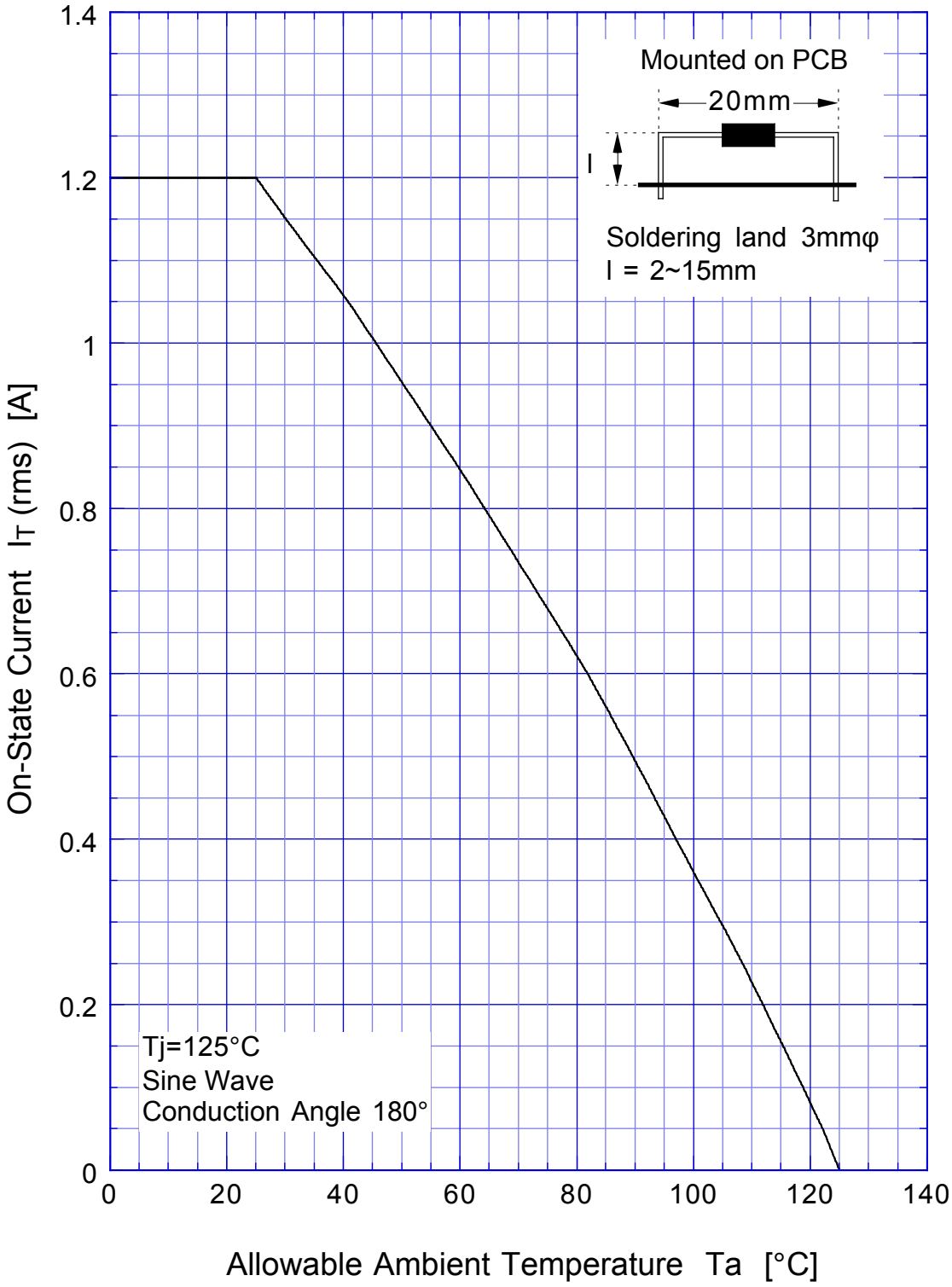
Maximum Ambient Temperature



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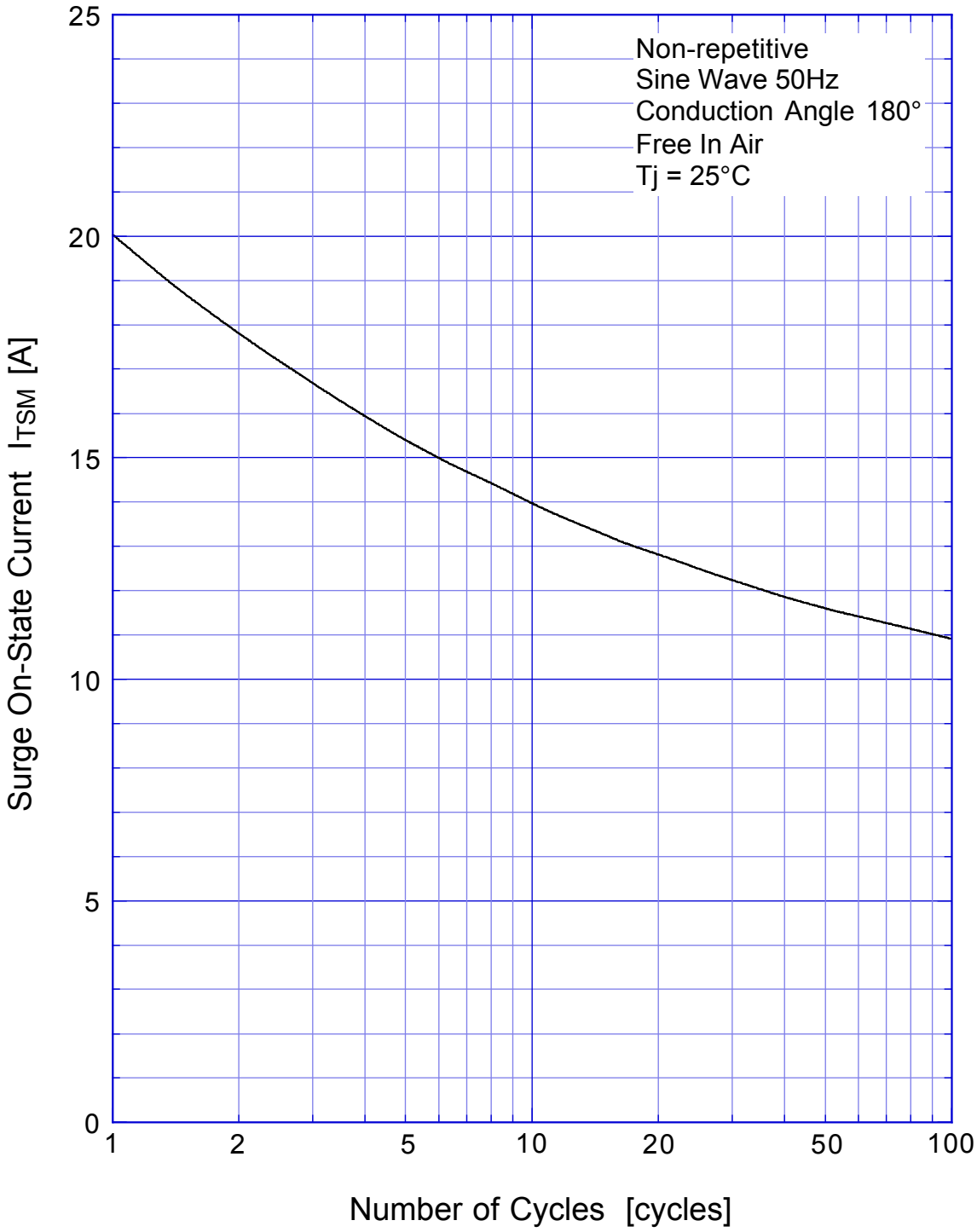
Maximum Surge On-State Current



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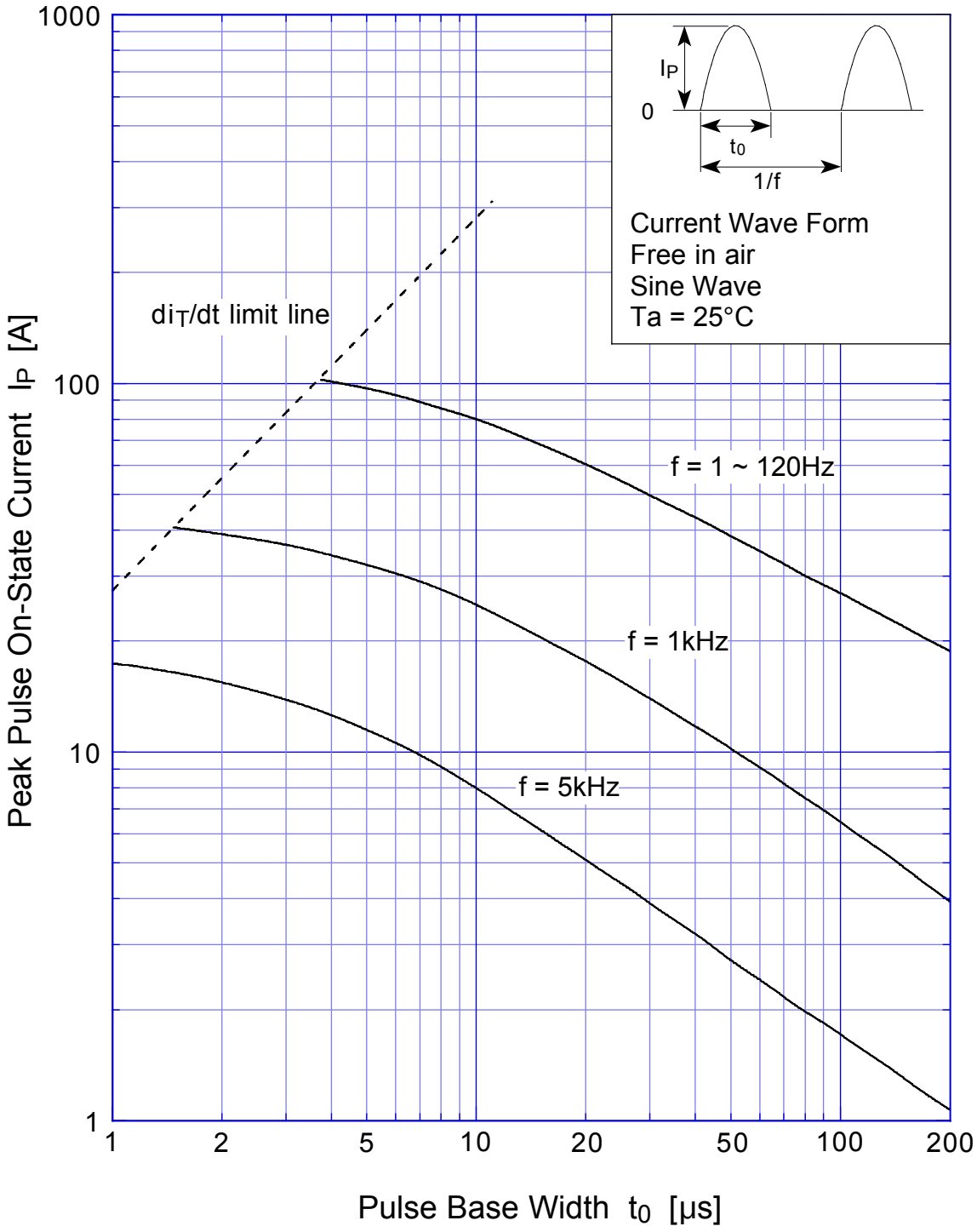
Pulse On-State Current Rating



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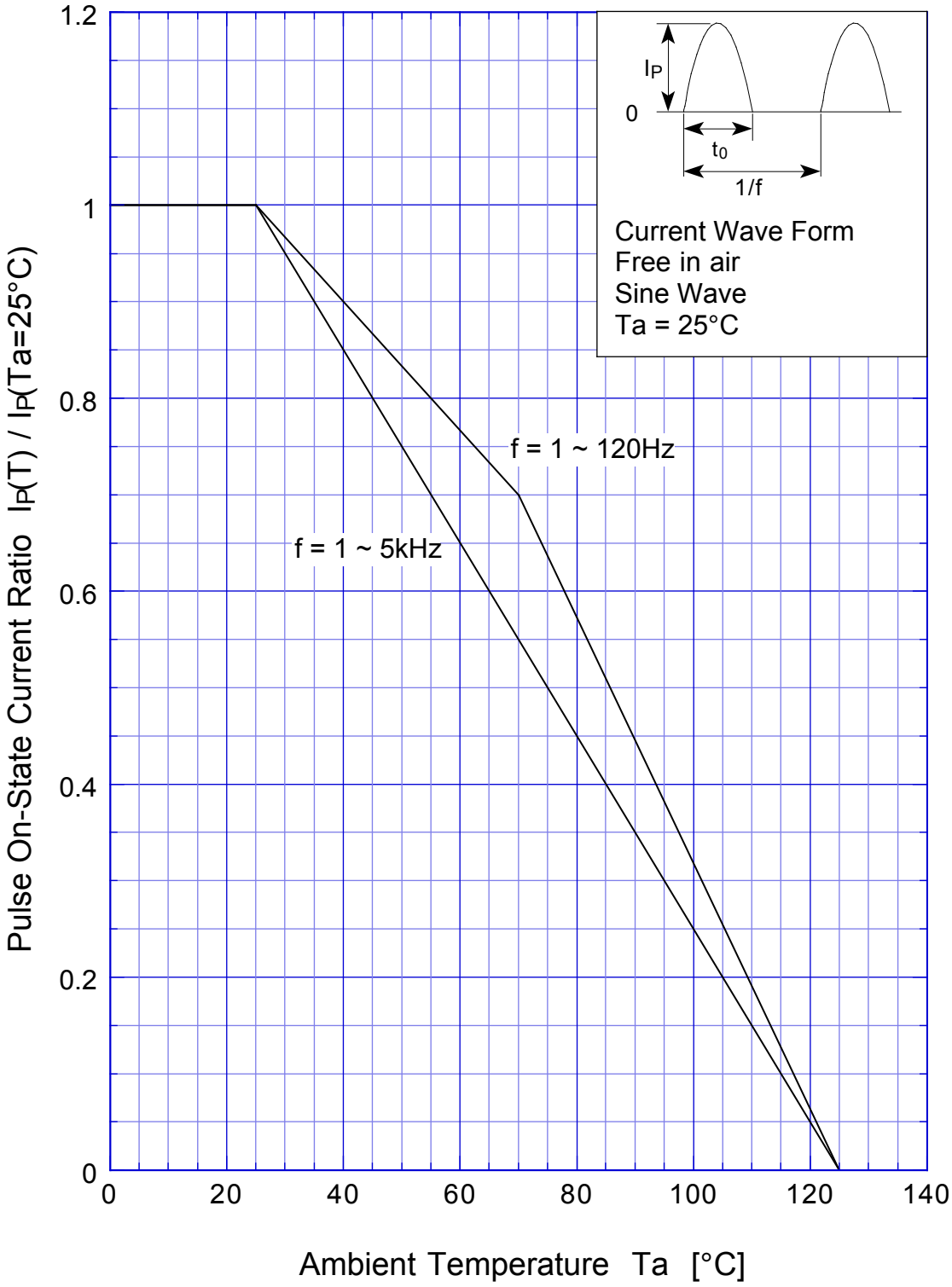
Pulse On-State Current Derating



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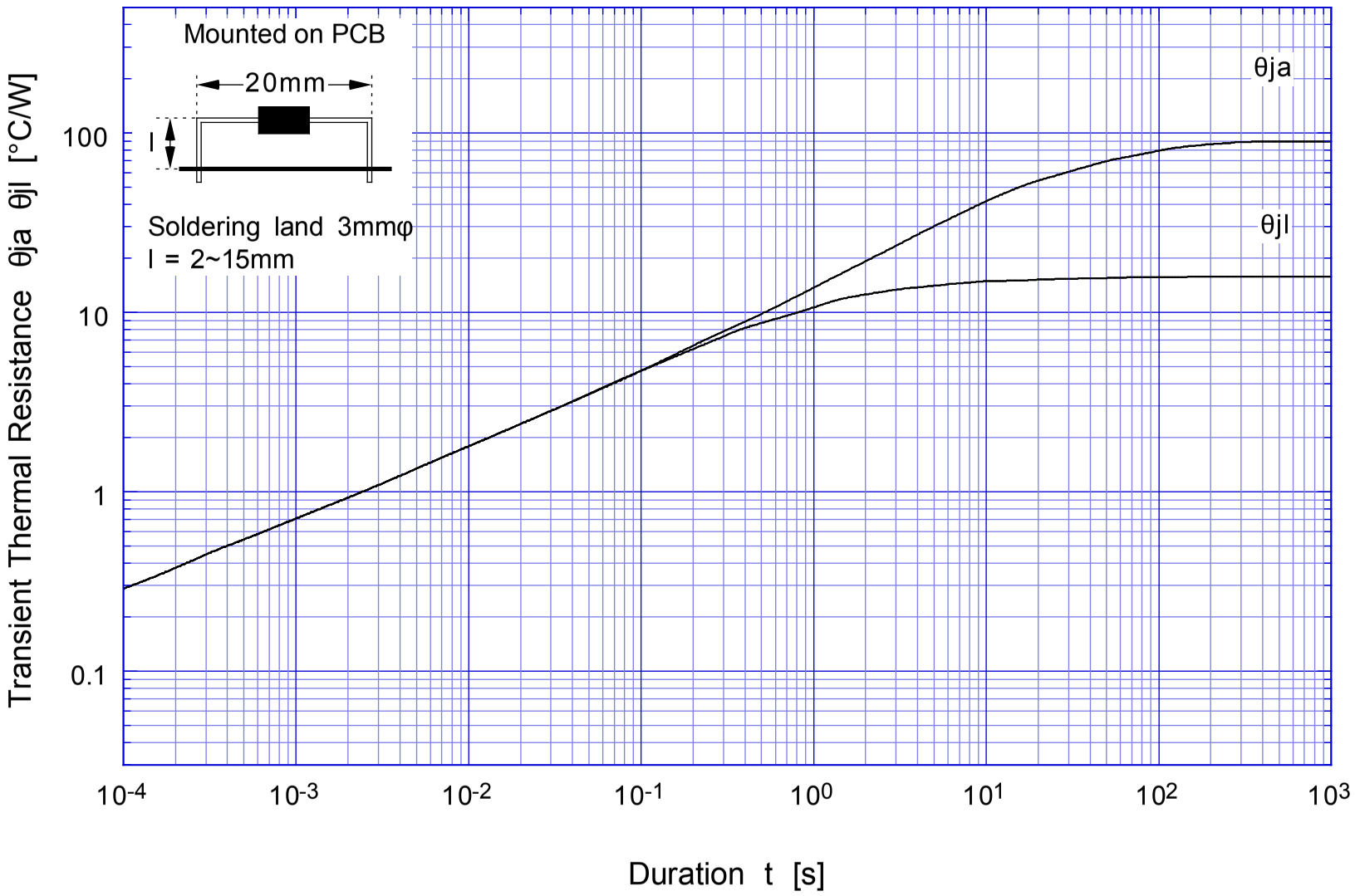
Transient Thermal Resistance



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Breakover Voltage - Junction Temperature